

3-Phase High Voltage Gate Drive IC

General description

The ID7T6036D is a three-phase gate drive IC which can be used to drive N-channel power MOSFETs or IGBTs in the high side configuration which operates up to 600V. Logic inputs are compatible with CMOS or LSTTL outputs, down to 3.3V logic. A current trip function which terminates all six outputs can be derived from an external current sense resistor. An enable function is available to terminate all six outputs simultaneously. An open-drain FAULT signal is provided to indicate that an over-current or under-voltage shutdown has occurred. Over-current fault conditions are cleared automatically after an internally delay. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications.

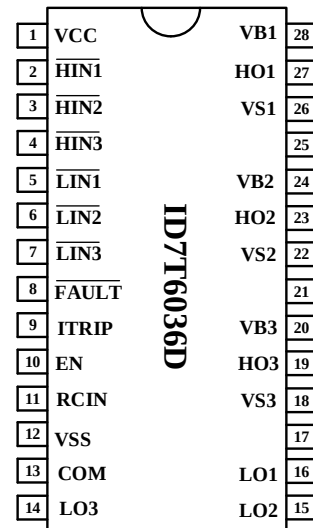
Features

- Operation to +600 V
- Typically 200mA/350mA Source/Sink current
- 3.3 V/5V/15V input logic compatible
- dV/dt Immunity ± 50 V/nsec
- Typically - 9V negative Vs bias capability
- Gate drive supply range from 13.2V to 20V
- UVLO for all channels
- Cross-conduction prevention logic
- Over-current shutdown turns off all six drivers
- Externally adjustable Fault-clear timing
- Built-in advanced input filter
- Matched propagation delay for all channels
- Built-in bootstrap diodes

Application

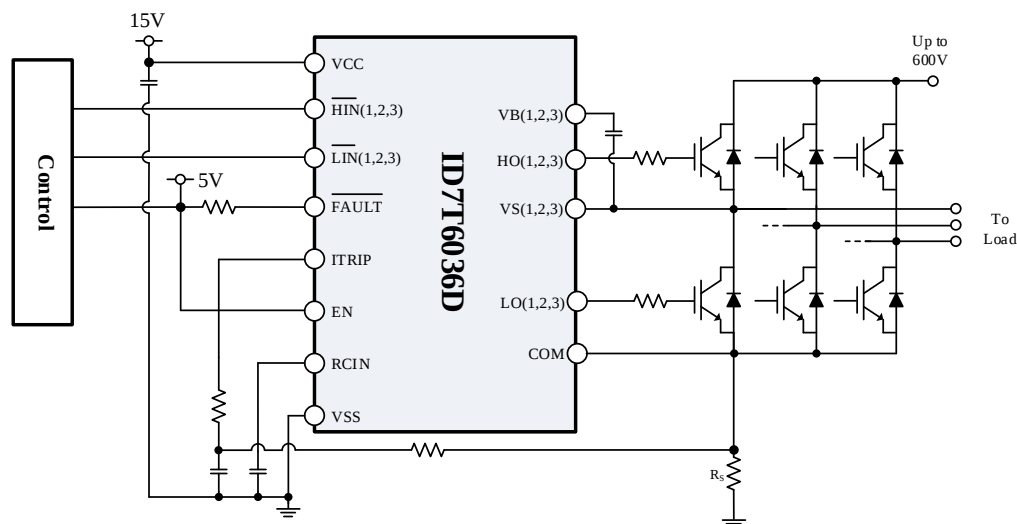
- Sewing Machine/Power Toll
- Air Conditioners/ Washing Machines /Refrigerator
- General Purpose Inverters

Package/Order Information



Order code	Package
ID7T6036DSAC-R1	SOP28

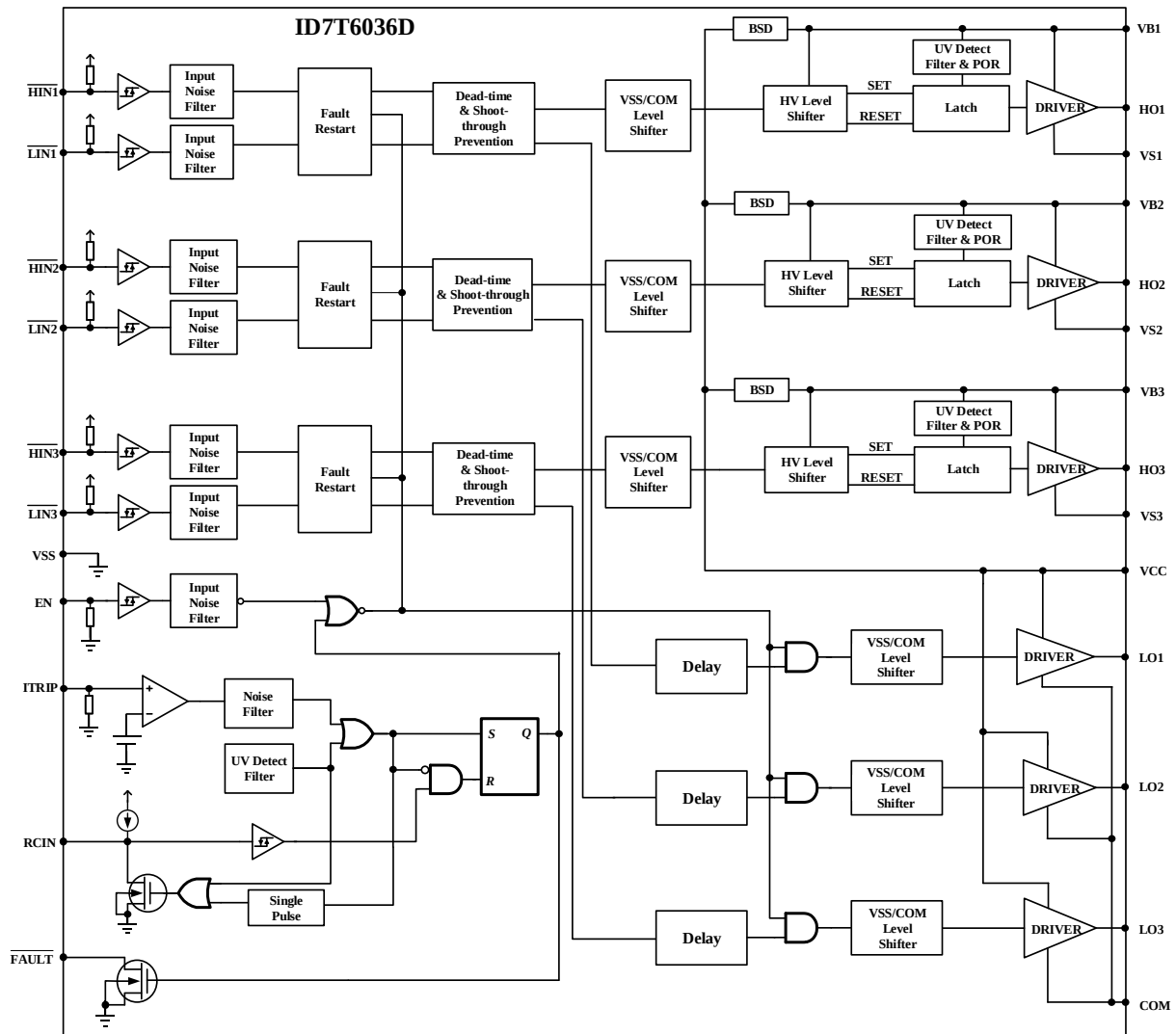
Typical Application Circuit



Pin Definitions

Pin Name	Pin Number	Pin Function Description
VCC	1	Low side and logic fixed supply voltage
$\overline{\text{HIN1}}$	2	Signal Input for 1 Phase High-side
$\overline{\text{HIN2}}$	3	Signal Input for 2 Phase High-side
$\overline{\text{HIN3}}$	4	Signal Input for 3 Phase High-side
$\overline{\text{LIN1}}$	5	Signal Input for 1 Phase Low-side
$\overline{\text{LIN2}}$	6	Signal Input for 2 Phase Low-side
$\overline{\text{LIN3}}$	7	Signal Input for 3 Phase Low-side
FAULT	8	Indicates over-current (ITRIP) or low-side under-voltage lockout
ITRIP	9	Analog input for overcurrent shutdown.
EN	10	Logic input to enable I/O functionality
RCIN	11	External RC network input used to define FAULT CLEAR delay
VSS	12	Logic ground
COM	13	Low side gate drivers return
LO3	14	Low side gate driver outputs for 3 Phase
LO2	15	Low side gate driver outputs for 2 Phase
LO1	16	Low side gate driver outputs for 1 Phase
VS3	18	High voltage floating supply return for 3 Phase
HO3	19	High side gate driver outputs for 3 Phase
VB3	20	High side floating supply for 3 Phase
VS2	22	High voltage floating supply return for 2 Phase
HO2	23	High side gate driver outputs for 2 Phase
VB2	24	High side floating supply for 2 Phase
VS1	26	High voltage floating supply return for 1 Phase
HO1	27	High side gate driver outputs for 1 Phase
VB1	28	High side floating supply for 1 Phase

Functional Block Diagram



Absolute Maximum Ratings

Exceeding these ratings may damage the device.

The absolute maximum ratings are stress ratings only at $T_A=25^{\circ}\text{C}$, unless otherwise specified.

Symbol	Definition	MIN.	MAX.	Units
$V_{B(1,2,3)}$	High side floating supply	-0.3	620	V
$V_{S(1,2,3)}$	High side floating supply return	$V_B - 20$	$V_B + 0.3$	
$V_{HO(1,2,3)}$	High side gate drive output	$V_S - 0.3$	$V_B + 0.3$	
V_{CC}	Low side and main power supply	-0.3	20	
$V_{LO(1,2,3)}$	Low side gate drive output	COM - 0.3	$V_{CC} + 0.3$	
V_{IN}	Logic input of $\overline{HIN}$ & $\overline{LIN}$	$V_{SS} - 0.3$	$V_{CC} + 0.3$	
V_{SS}	Logic ground	$V_{CC} - 20$	$V_{CC} + 0.3$	
V_{RCIN}	RCIN input voltage	V_{SS}	V_{CC}	
V_{FLT}	$\overline{FAULT}$ output voltage	$V_{SS} - 0.3$	$V_{CC} + 0.3$	V/ns
d V_S /dt	Allowable Offset Supply Voltage Transient	—	50	
ESD	HBM Model	2.5	—	kV
	Machine Model	200	—	V
P_D	Package Power Dissipation @ $T_A \leq 25^{\circ}\text{C}$ (28 Lead SOP)	—	1.6	W
R_{thJA}	Thermal Resistance Junction to Ambient(28 Lead SOP)	—	78	$^{\circ}\text{C}/\text{W}$
T_J	Junction Temperature	—	150	$^{\circ}\text{C}$
T_S	Storage Temperature	-55	150	
T_L	Lead Temperature (Soldering, 10 seconds)	--	300	

Recommended Operating Conditions

Symbol	Definition	Min.	Max.	Units
$V_{B(1,2,3)}$	High side floating supply	$V_S + 10$	$V_S + 20$	V
$V_{S(1,2,3)}$	High side floating supply return	COM - 9	600	
$V_{HO(1,2,3)}$	High side gate drive output voltage	$V_{S(1,2,3)}$	$V_{B(1,2,3)}$	
V_{CC}	Low side supply	13.2	20	
$V_{LO(1,2,3)}$	Low side gate drive output voltage	0	V_{CC}	
V_{IN}	Logic input voltage($\overline{HIN}$ & $\overline{LIN}$)	0	V_{CC}	
V_{SS}	Logic ground	-5	5	
V_{RCIN}	RCIN input voltage	V_{SS}	V_{CC}	
V_{FLT}	$\overline{FAULT}$ output voltage	V_{SS}	V_{CC}	$^{\circ}\text{C}$
T_A	Ambient temperature	-40	125	

Dynamic Electrical Characteristics

(V_{BIAS} (V_{CC} , V_{BS}) = 15V, C_L = 1000 pF and T_A = 25 °C unless otherwise specified.)

Symbol	Definition	MIN.	TYP.	MAX.	Units
t_{ON}	Turn on propagation delay	400	530	750	ns
t_{OFF}	Turn off propagation delay	400	530	750	
t_R	Turn on rising time	-	125	190	
t_F	Turn off falling time	-	50	75	
$t_{IN,FLT}$	Input filter time ($\overline{HIN}$, $\overline{LIN}$)	200	350	510	
t_{EN}	Enable low to output shutdown propagation delay	350	460	650	
$t_{EN,FLT}$	Enable input filter time	100	200	-	
t_{UVCC}	UVCC filter time	-	7	-	μ s
t_{UVBS}	UVBS filter time	-	7	-	
$t_{UVCC,FO}$	UVCC to FAULT shutdown propagation delay	-	7	-	
$t_{UVCC,LO}$	UVCC to LO shutdown propagation delay	-	7	-	
$t_{UVBS,HO}$	UVBS to HO shutdown propagation delay	-	7	-	
t_{FOD}	FAULT output duration time (RCIN: C = 1nF)	1.3	1.95	2.5	ms
t_{ITRIP}	ITRIP to output shutdown propagation delay	420	620	970	ns
$t_{IT,FLT}$	ITRIP filter time	-	400	-	
t_{FO}	ITRIP to FAULT propagation delay	400	600	950	
DT	Dead time	190	275	420	
MDT	DT Matching	-	-	60	
MT	Delay matching time (t_{ON} , t_{OFF})	-	-	50	
PM	Pulse width distortion ^[1]	-	-	75	

Notes:

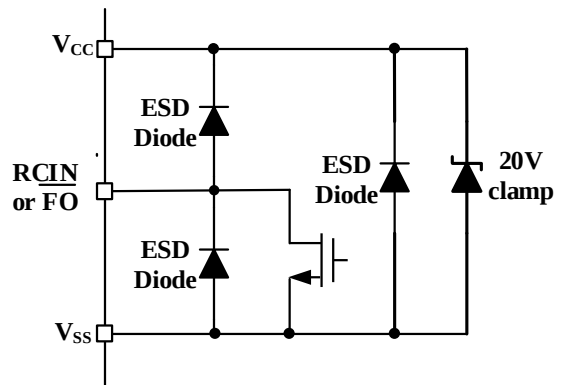
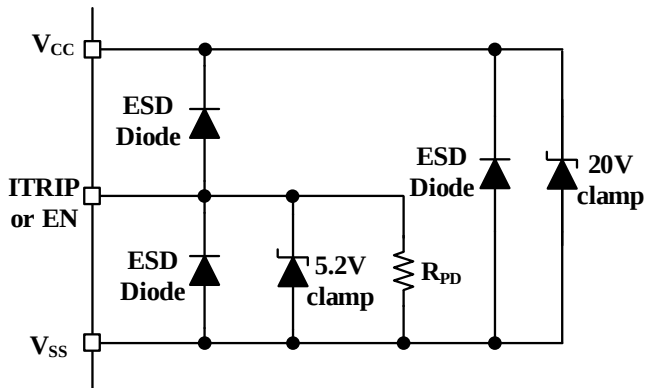
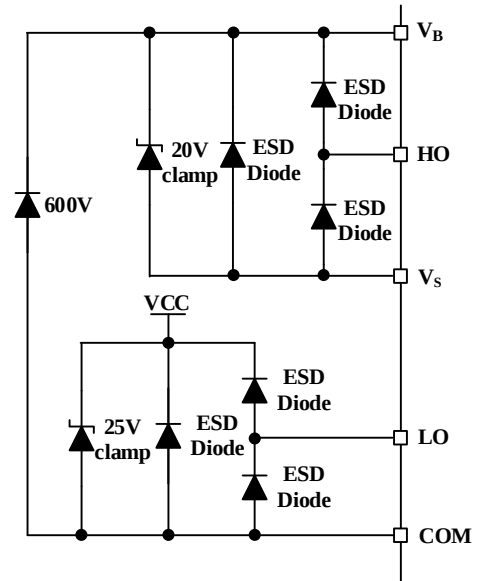
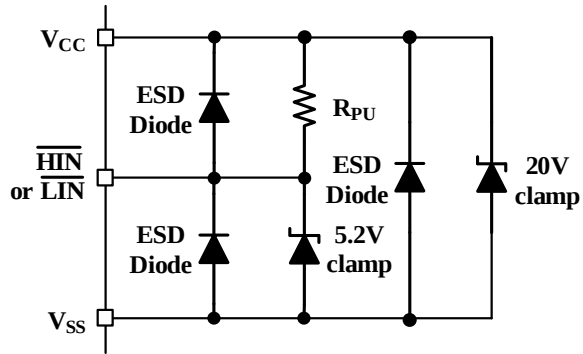
1. PM is defined as $PW_{IN} - PW_{OUT}$.

Static Electrical Characteristics

(V_{BIAS} (V_{CC}, V_{BS}) = 15V, C_L = 1000 pF and T_A = 25 °C unless otherwise specified.)

Symbol	Definition	MIN.	TYP.	MAX.	Units
V _{UVCC+}	V _{CC} supply undervoltage positive going threshold	8	8.9	9.8	V
V _{UVCC-}	V _{CC} supply undervoltage negative going threshold	7.4	8.2	9.0	
V _{UVCCHY}	V _{CC} supply undervoltage hysteresis	0.3	0.7	-	
I _{LK}	High-side floating supply leakage current	-	-	50	μA
I _{QBS}	Quiescent V _{BS} supply current	-	70	120	
I _{QCC}	Quiescent V _{CC} supply current	-	1	2	mA
I _{PBS}	Operating V _{BS} supply current	-	400	600	μA
I _{PCC}	Operating V _{CC} supply current (per 1phase)	-	1.3	1.8	mA
V _{OH}	High level output voltage drop, V _{BIAS} - V _O	-	0.9	1.4	V
V _{OL}	Low level output voltage drop, V _O	-	0.4	0.6	
I _{O+}	Output high short circuit pulsed current	120	200	-	mA
I _{O-}	Output low short circuit pulsed current	250	350	-	
V _{IH}	High level input threshold voltage	2.5	-	-	V
V _{IL}	Low level input threshold voltage	-	-	0.8	
V _{CLAMP}	Input clamp voltage ($\overline{\text{HIN}}$, $\overline{\text{LIN}}$, ITRIP, EN)	5.2	5.6	5.9	
I _{HIN+}	Input bias current (HO = High)	-	150	200	μA
I _{HIN-}	Input bias current (HO = Low)	-	110	150	
I _{LIN+}	Input bias current (LO = High)	-	150	200	
I _{LIN-}	Input bias current (LO = Low)	-	110	150	
V _{RCIN,TH}	RCIN positive going threshold	-	5.25	-	V
V _{RCIN,HY}	RCIN hysteresis	-	3	-	
I _{RCIN}	RCIN internal current source	2	3	4	μA
R _{RCIN,ON}	RCIN low on resistance	-	50	100	Ω
V _{IT,TH+}	ITRIP positive going threshold	0.42	0.46	0.5	V
V _{IT,TH-}	ITRIP negative going threshold	-	0.4	0.49	
V _{IT,HY}	ITRIP hysteresis	-	0.06	-	
I _{ITRIP+}	“High” ITRIP input bias current	-	5	40	μA
I _{ITRIP-}	“Low” ITRIP input bias current	-	-	1	
V _{EN,TH+}	Enable positive going threshold	-	-	2.5	V
V _{EN,TH-}	Enable negative going threshold	0.8	-	-	
I _{EN+}	“High” Enable input bias current	-	5	40	μA
I _{EN-}	“Low” Enable input bias current	-	-	1	
R _{FO,ON}	FAULT low on resistance	-	50	100	Ω
R _{BSD}	Internal Bootstrap Equivalent Resistor Value	-	200	-	Ω

Input / Output Pin Equivalent Circuit Diagrams



Function Timing Diagram

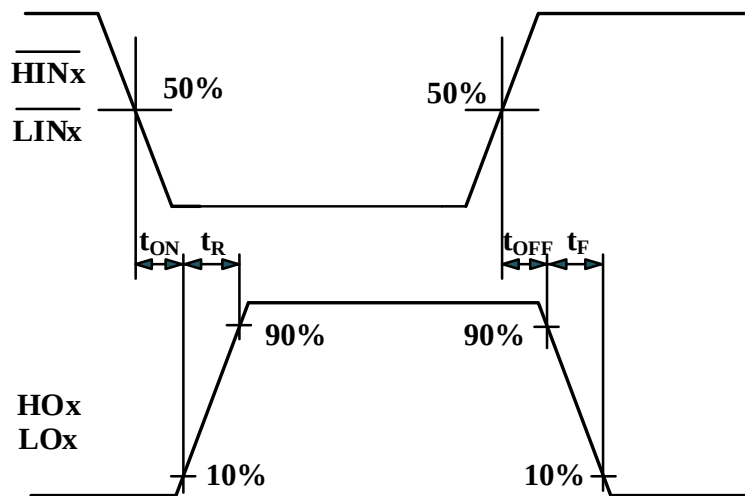


Fig.1 Switching timing waveform

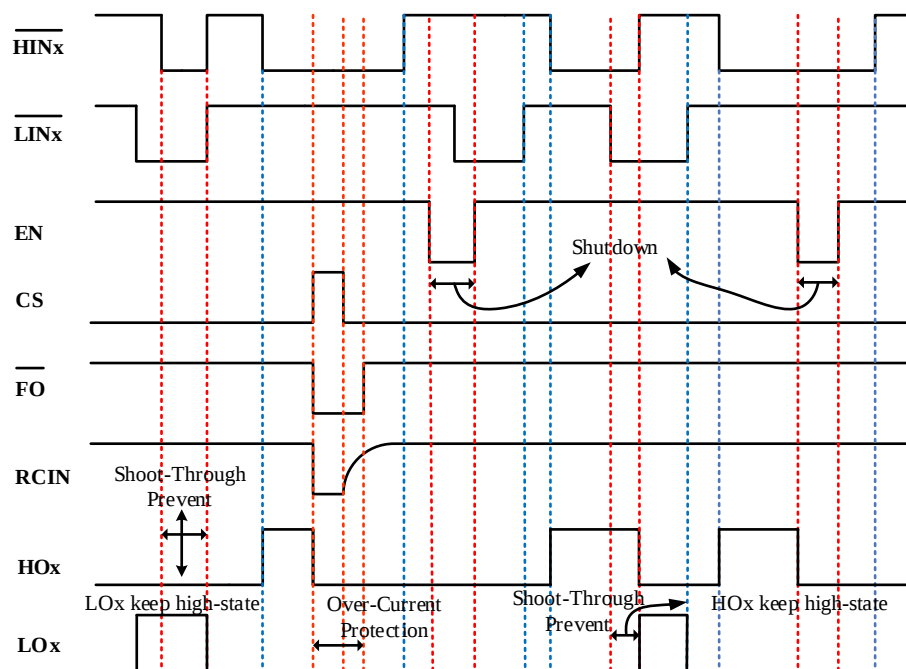


Fig.2 Input / Output timing waveform

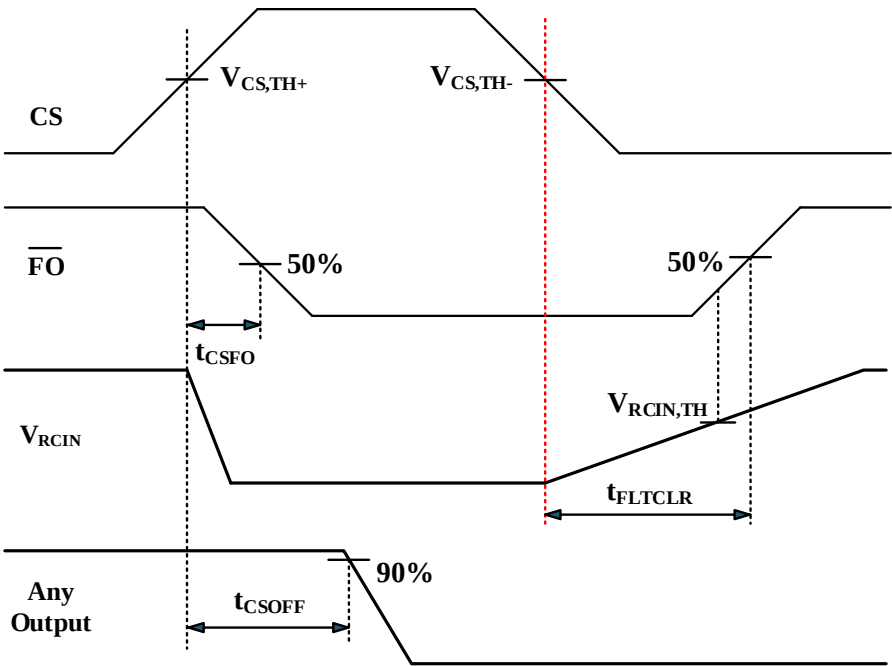


Fig.3 Delay Time During Over-Current Protection

Characterization Curves

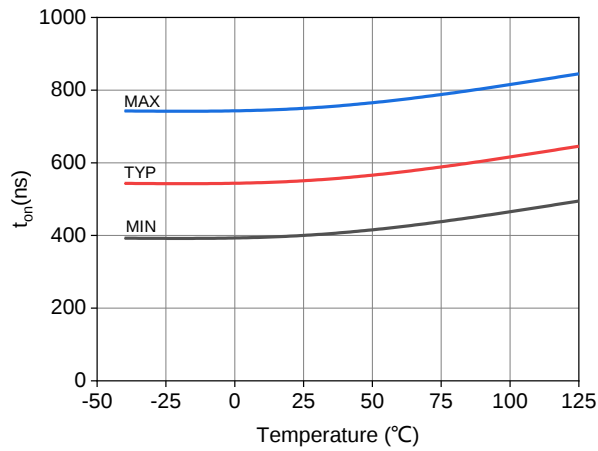


Fig.4 t_{ON} vs. temperature

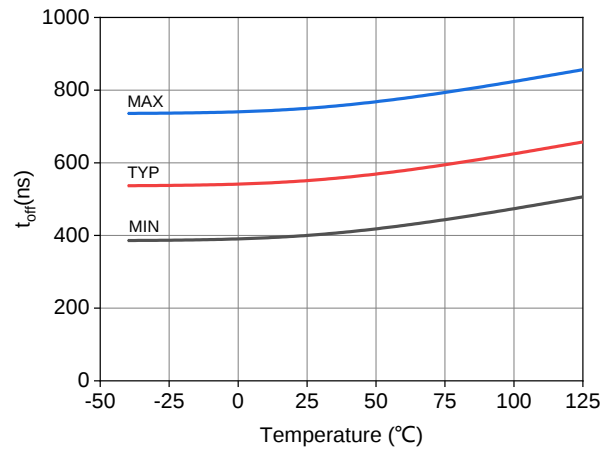


Fig.5 t_{OFF} vs. temperature

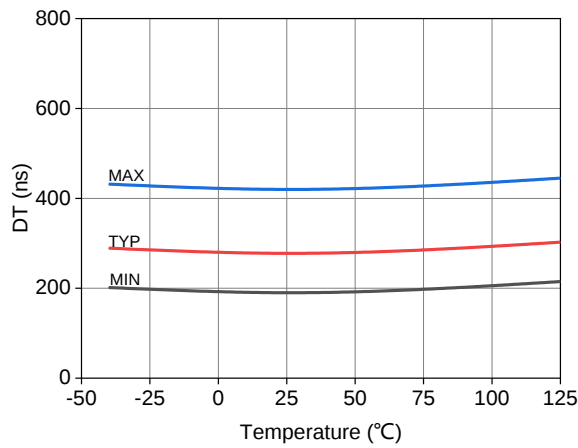


Fig.6 DT vs. temperature

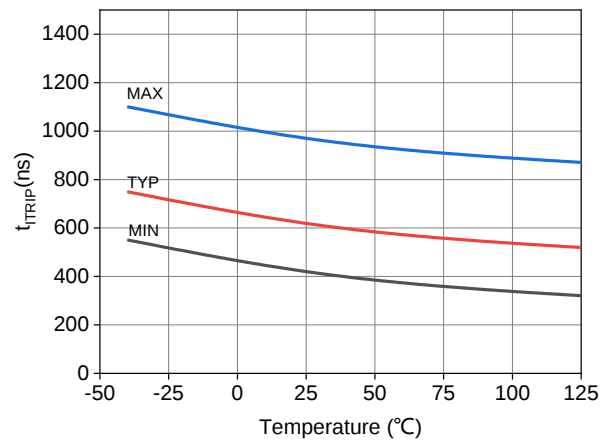


Fig.7 t_{TRIP} vs. temperature

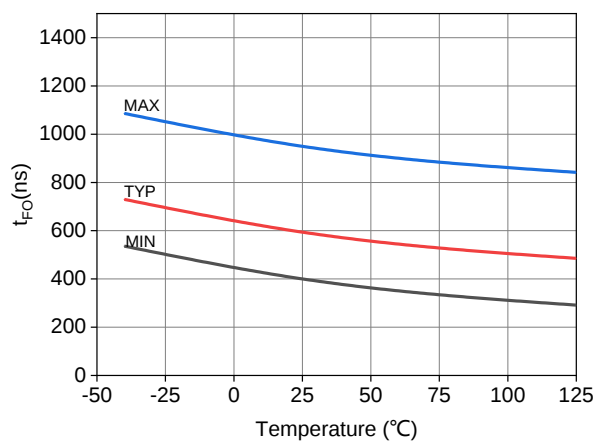


Fig.8 t_{FO} vs. temperature

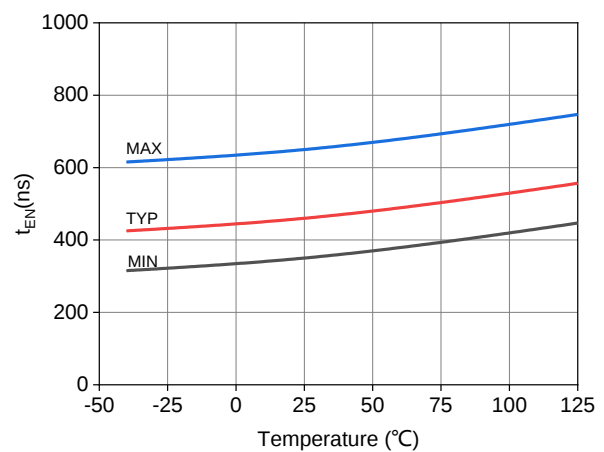


Fig.9 t_{EN} vs. temperature

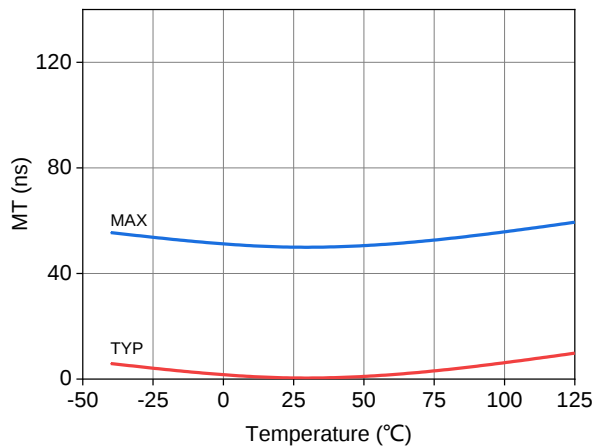


Fig.10 MT vs. temperature Figure

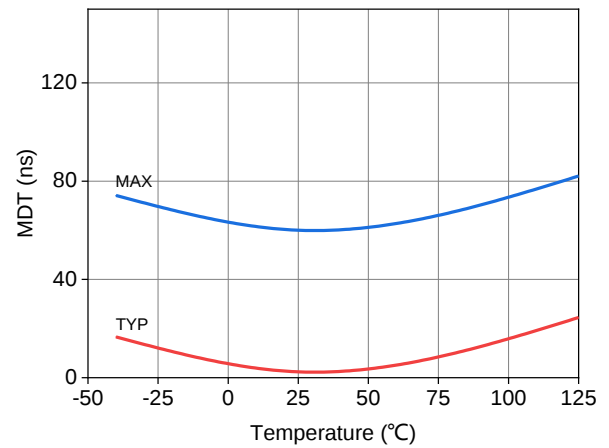


Fig.11 MDT vs. temperature

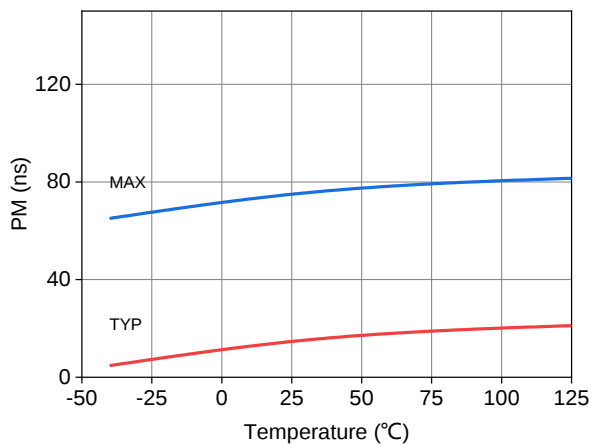


Fig.12 PM vs. temperature Figure

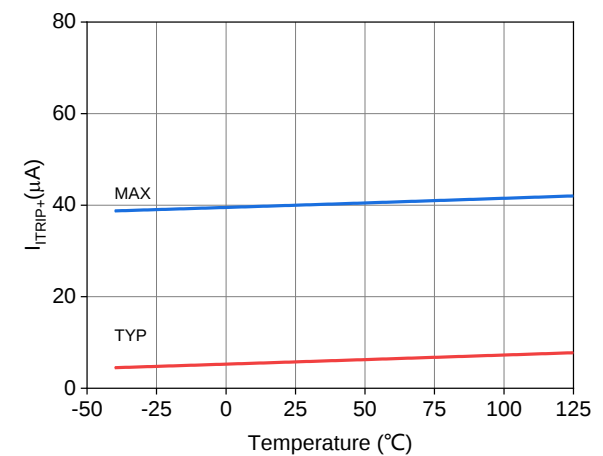


Fig.13 I_{TRIP+} vs. temperature

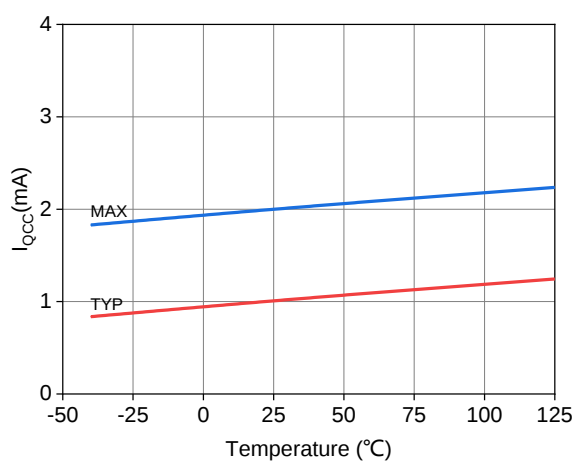


Fig.14 I_{QCC} vs. temperature Figure

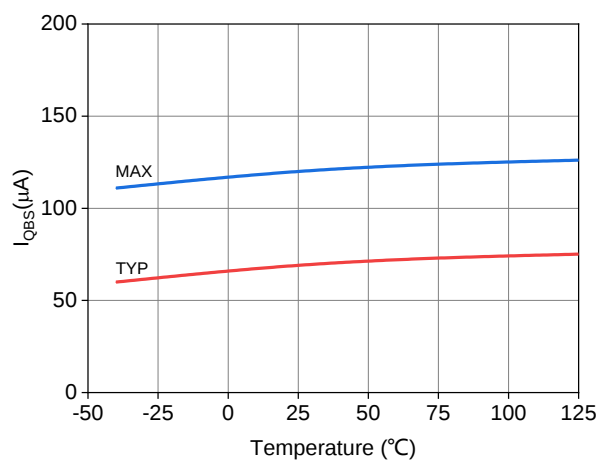


Fig.15 I_{QBS} vs. temperature

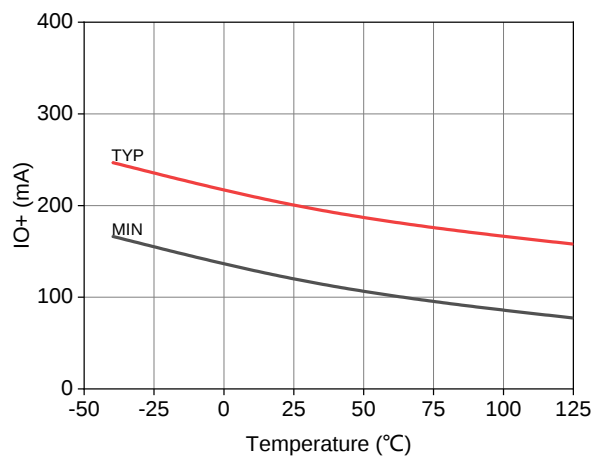


Fig.16 IO+ vs. temperature Figure

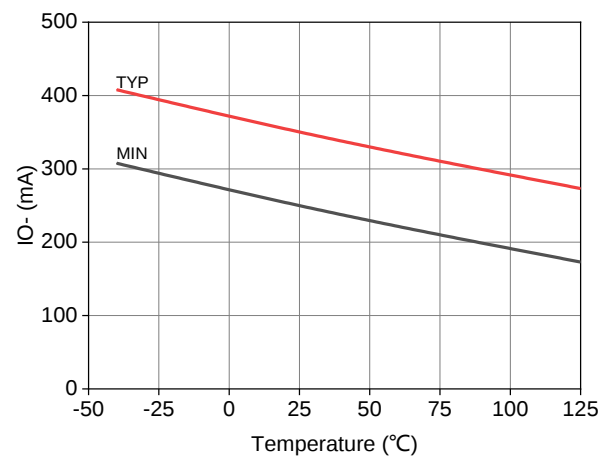


Fig.17 IO- vs. temperature

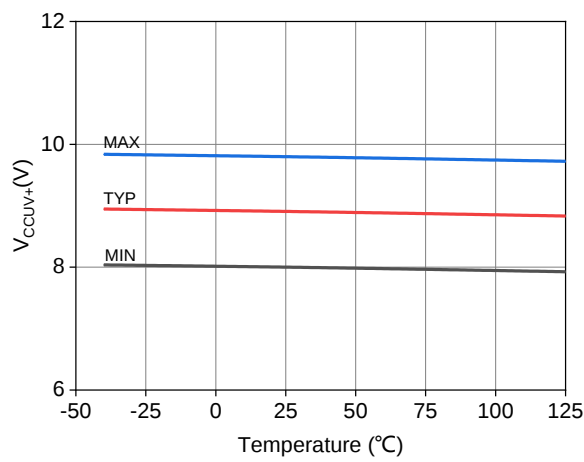


Fig.18 VCCUV+ vs. temperature Figure

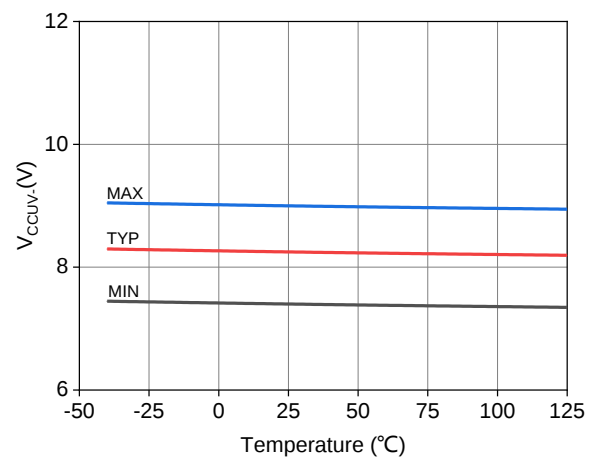


Fig.19 VCCUV- vs. temperature

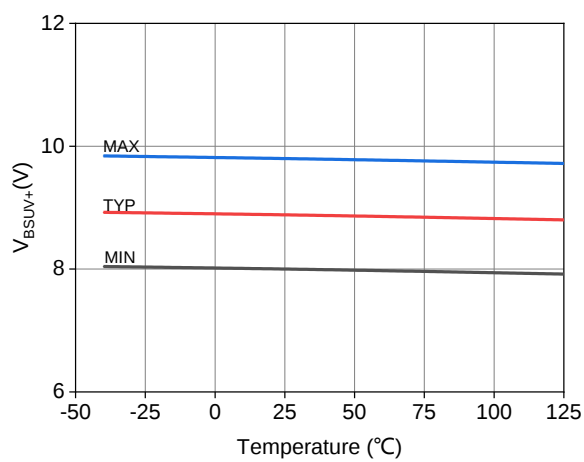


Fig.20 VBSUV+ vs. temperature Figure

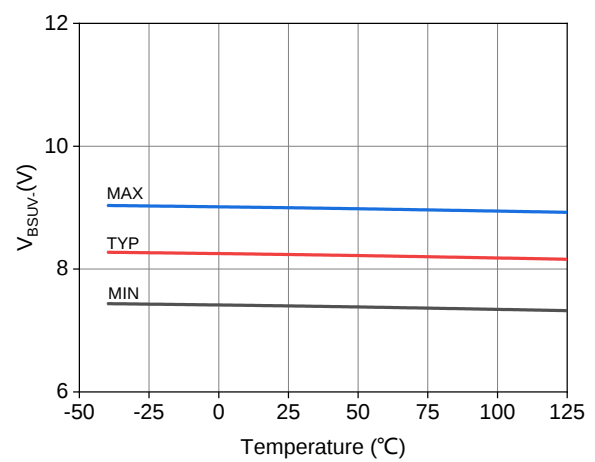


Fig.21 VBSUV- vs. temperature

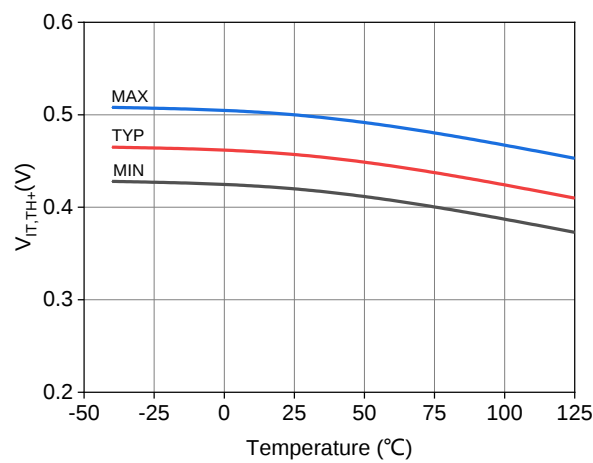


Fig.22 $V_{IT,TH+}$ vs. temperature

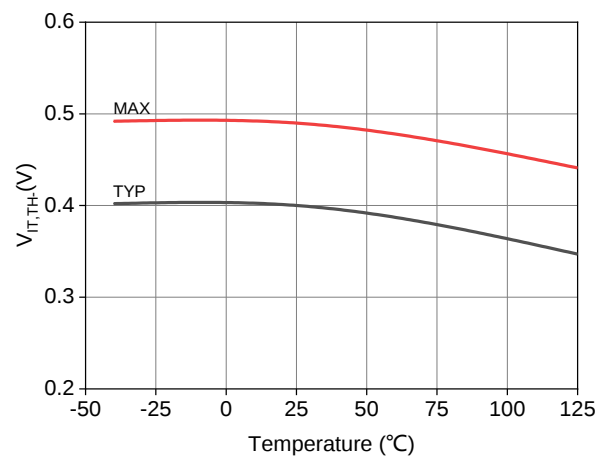


Fig.23 $V_{IT,TH-}$ vs. temperature

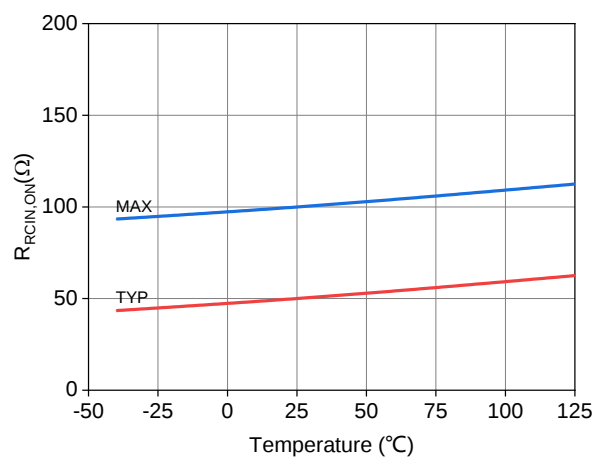


Fig.24 $R_{RCIN,ON}$ vs. temperature

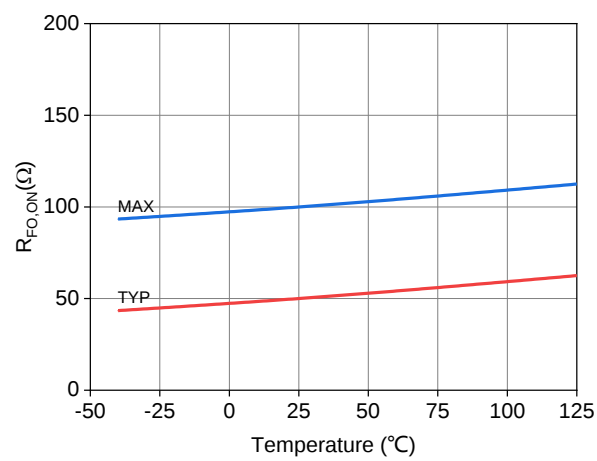
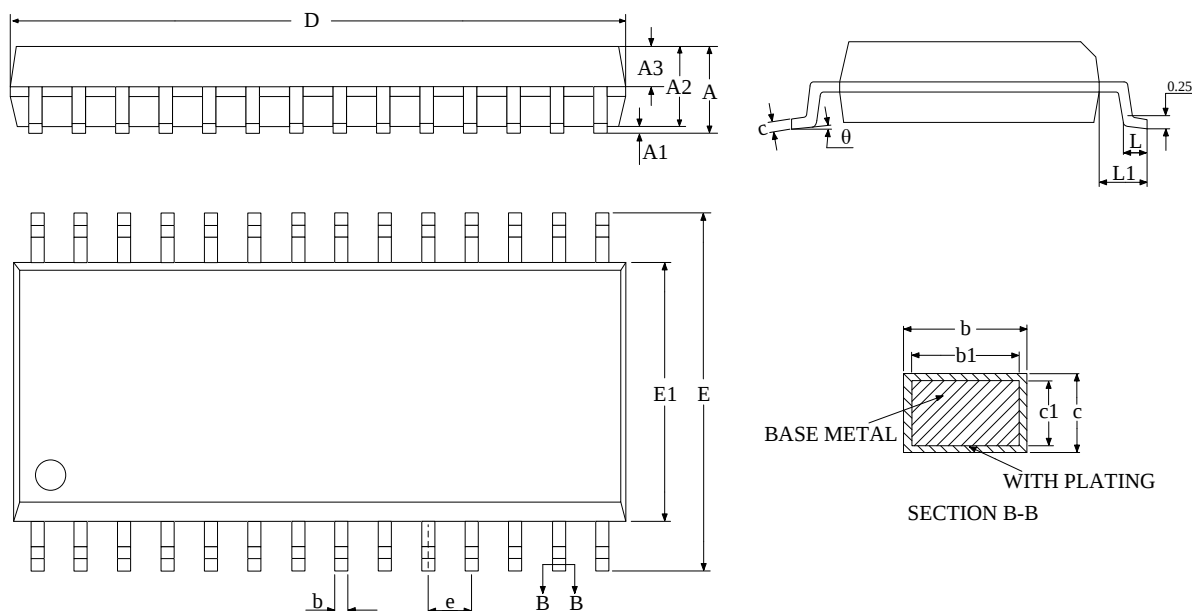


Fig.25 $R_{FO,ON}$ vs. temperature

Package Information

Package Information SOP28



Symbol	Size	Min. (mm)	Typ. (mm)	Max. (mm)	Symbol	Size	Min. (mm)	Typ. (mm)	Max. (mm)
A	-	-	-	2.65	D	-	17.89	18.09	18.29
A1	-	0.10	-	0.30	E	-	10.10	10.30	10.50
A2	-	2.25	2.30	2.35	E1	-	7.30	7.50	7.70
A3	-	0.97	1.02	1.07	e	1.27BSC			
b	-	0.39	-	0.48	L	-	0.70	-	1.00
b1	-	0.38	0.41	0.43	L1	1.40BSC			
c	-	0.25	-	0.31	θ	-	0	-	8°
c1	-	0.24	0.25	0.26					

Top mark	Package
iDR. ID7T6036D YWWXXXXX	SOP28

Note: Y: Year Code; WW: Week Code; XXXXX: Internal Code

Notes:

1. This drawing is subjected to change without notice.
2. Body dimensions do not include mold flash or protrusion.

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